

# PARA LIGHT ELECTRONICS CO., LTD.

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# DATA SHEET

# PART NO.: L-S115KFLBCT-U1

# REV: <u>A / 2</u>

CUSTOMER'S APPROVAL :

DCC :

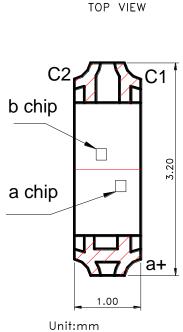
DRAWING NO. : DS-78-15-0001

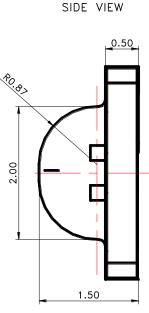


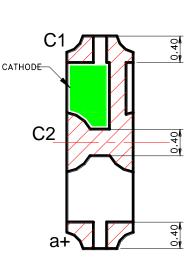
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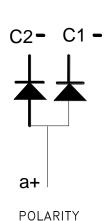
#### • PACKAGE OUTLINE DIMENSIONS







BACK VIEW



Tolerance:±0.10

#### Notes:

1. a chip: Super Amber.; b chip: Blue

- 2. All dimensions are in millimeters.
- 3. Tolerance is  $\pm$  0.1mm (.004") unless otherwise noted.

#### • Features

- \* Dual color, <u>common anode</u>, side view Chip LED.
- \* Package in 8mm tape on 7" diameter reels.
- \* Compatible with automatic Pick & Place equipment.
- \* Compatible with Reflow soldering and Wave soldering processes.
- \* EIA STD package.
- \* I.C. compatible.
- \* Pb free product.
- \* Meet RoHS Green Product.
- \* Moisture sensitivity level: 3

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#### • Chip Materials

chip	Light Color	Dice Material	Lens Color	
a	KF: Super Amber	AlInGaP	Water Clear	
b	LB: Blue	InGaN	Water Clear	

#### • Absolute Maximum Ratings(Ta=25°C)

Symbol	Parameter	R	Unit	
	Falameter	Blue	Super Amber	Unit
PD	Power Dissipation	100	75	mW
Ipf	Peak Forward Current	100	80	mA
IPF	(1/10 Duty Cycle, 0.1ms Pulse Width)	100	80	IIIA
IF	Continuous Forward Current	25	30	mA
VR	Reverse Voltage	5	5	V
ESD	Electrostatic Discharge Threshold(HBM) <sup>Note A</sup>	1000	2000	V
Topr	Operating Temperature Range	-40 ~ +85		°C
Tstg	Storage Temperature Range	-40 ~ +85		°C

Note A:

HBM: Human Body Model. Seller gives no other assurances regarding the ability of to withstand ESD

#### • Electro-Optical Characteristics(Ta=25°C)

Parameter	Symbol	Super Amber	Blue	Unit	Test Condition	
	Min.		71	71		IF=20mA
Luminous Intensity	Тур.	IV	180	150	mcd	
	Max.		280	280		
Viewing Angle	Тур.	2 <b>θ</b> 1/2	130		deg	Note 2
	Min.		600	465		
Dominant Wavelength	Тур.	λd	605	470	nm	IF=20mA
	Max.		610	475		
Spectral Line Half-Width	Тур.	Δλ	17	25	nm	
	Min		1.8	2.8		
Forward Voltage	Тур.	VF	2.0	3.0	- V	IF =20mA
	Max.		2.3	3.4	v	
Reverse Current	Max.	IR	10	50	μA	VR = 5V
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#### • Bin Code List

Luminous Intensity(IV), Unit:mcd@20mA						
Super Amber (a chip)				Blue (b chip)		
Bin Code	Min	Max	Bin Code	Min	Max	
Q	71.0	112.0	Q	71.0	112.0	
R	112.0	180.0	R	112.0	180.0	
S	180.0	280.0	S	180.0	280.0	

Tolerance of each bin are  $\pm 15\%$ 

Dominant Wavelength (Hue),Unit: nm@20mA						
Super Amber (a chip)			Blue (b chip)			
Bin Code	Min	Max	Bin Code	Min	Max	
OA	600	605	AC	465	470	
OB	605	610	AD	470	475	

Tolerance of each bin are  $\pm 1$ nm

Notes:

- 1. Luminous intensity is measured with a light sensor and filter combination that proximities the CIE eye-response curve.
- 2.  $\theta_{1/2}$  is the off-axis angle at which the luminous intensity is half the axial luminous intensity.
- 3. The dominant wavelength  $\lambda d$  is derived from the CIE chromaticity diagram and represents the single wavelength which defines the color of the device.
- 4. Caution in ESD :

Static Electricity and surge damages the LED. It is recommended use a wrist band or anti-electrostatic glove when handling the LED. All devices, equipment and machinery must be properly grounded.

5. Major standard testing equipment by "Instrument System" Model : CAS140B Compact Array Spectrometer and "KEITHLEY" Source Meter Model : 2400.

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#### • Super Amber Typical Electro-Optical Characteristics Curves

(25°CAmbient Temperature Unless Otherwise Noted)

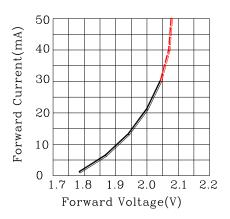


Fig.2 Forward Current vs.Forward Voltage

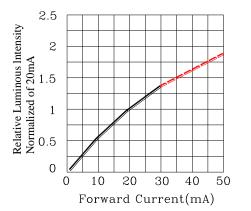
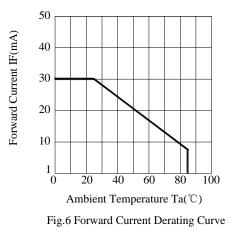


Fig.4 Relative Luminous Intensity vs.Forward Current



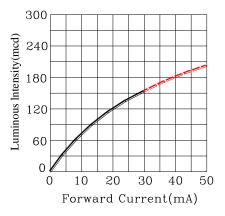


Fig.3 Luminous Intensity vs.Forward Current

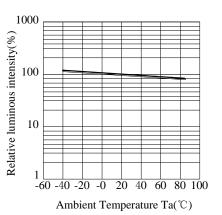


Fig.5 Luminous Intensity vs.Ambient Temperature

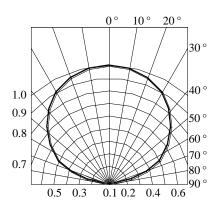


Fig.7 Relative Intensity vs.Angle

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#### SURFACE MOUNT DEVICE LED

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#### Blue Typical Electro-Optical Characteristics Curves (25°CAmbient Temperature Unless Otherwise Noted) 50 375 Forward Current(mA) Luminous Intensity(mcd) 40 300 30 225 20 150 10 75 0 ∟ 2.6 0 2.8 3.0 3.2 3.4 3.6 20 30 0 10 Forward Voltage(V) Fig.2 Forward Current vs.Forward Voltage 1000 2.5 Relative Luminous Intensity Normalized of 20mA 5 C C C C C C C Relative luminous intensity(%) 100 10 0 1 0 10 20 30 40 50 Forward Current(mA) Fig.4 Relative Luminous Intensity vs.Forward Current 0° 50 Forward Current IF(mA) 40 30 1.0 25 0.9 20 0.8 10 0.7 0 80 100 0 $\overline{20}$ 40 60 0.5 0.3 0.1 0.2 Ambient Temperature Ta(°C) Fig.6 Forward Current Derating Curve DRAWING NO. : DS-78-15-0001 DATE : 2021-11-25

40 50 Forward Current(mA) Fig.3 Luminous Intensity vs.Forward Current

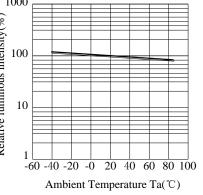


Fig.5 Luminous Intensity vs.Ambient Temperature

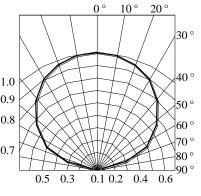


Fig.7 Relative Intensity vs.Angle

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#### Part No. : L-S115KFLBCT

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#### • Label Explanation



LOT NO:  $\frac{\text{EM S L}}{\text{A B C D E F}} \begin{array}{c} 09 \\ \text{F} \end{array}$ 

A---EM: Emos Code

B---S:SMD

C---Local

D---Year

E---Month

F---SPEC.

PACKING QUANTITY OF BAG :

3000pcs for 150, 170, 110, 155, 115 series

4000pcs for 191 series

5000pcs for 192 series

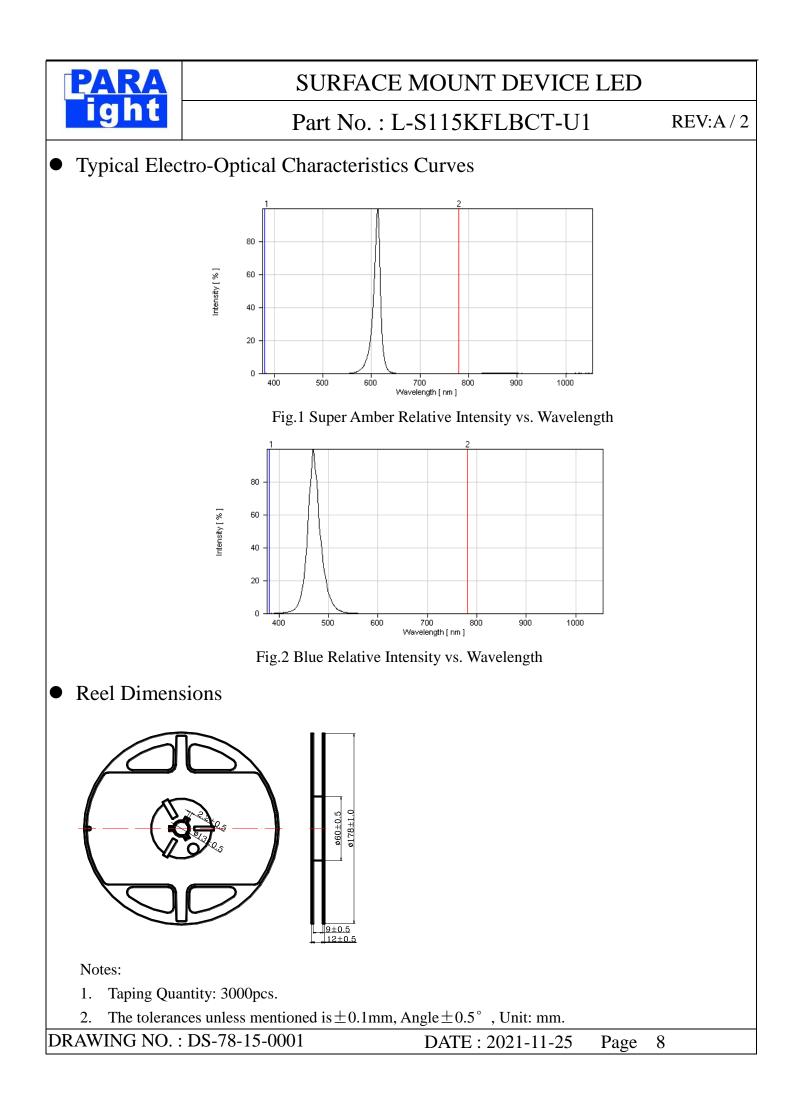
DATE CODE: <u>2012</u> <u>09</u> <u>10</u>

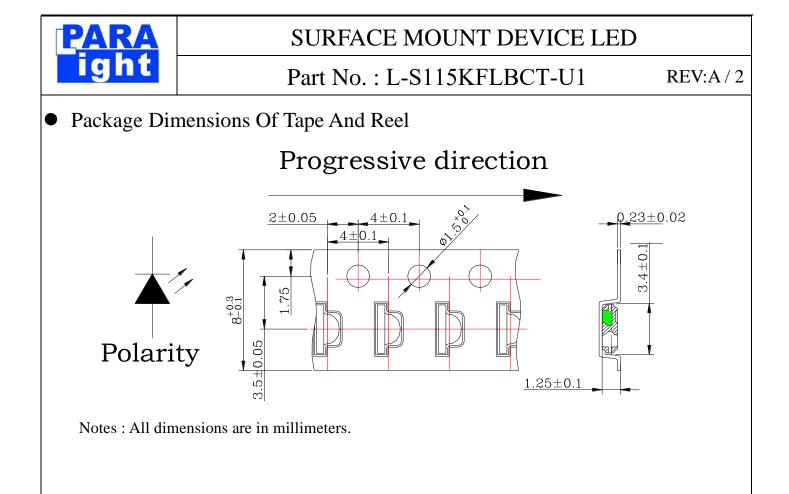
G H I

G--- Year H--- Month

I --- Day

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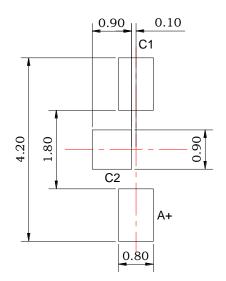
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#### • Cleaning

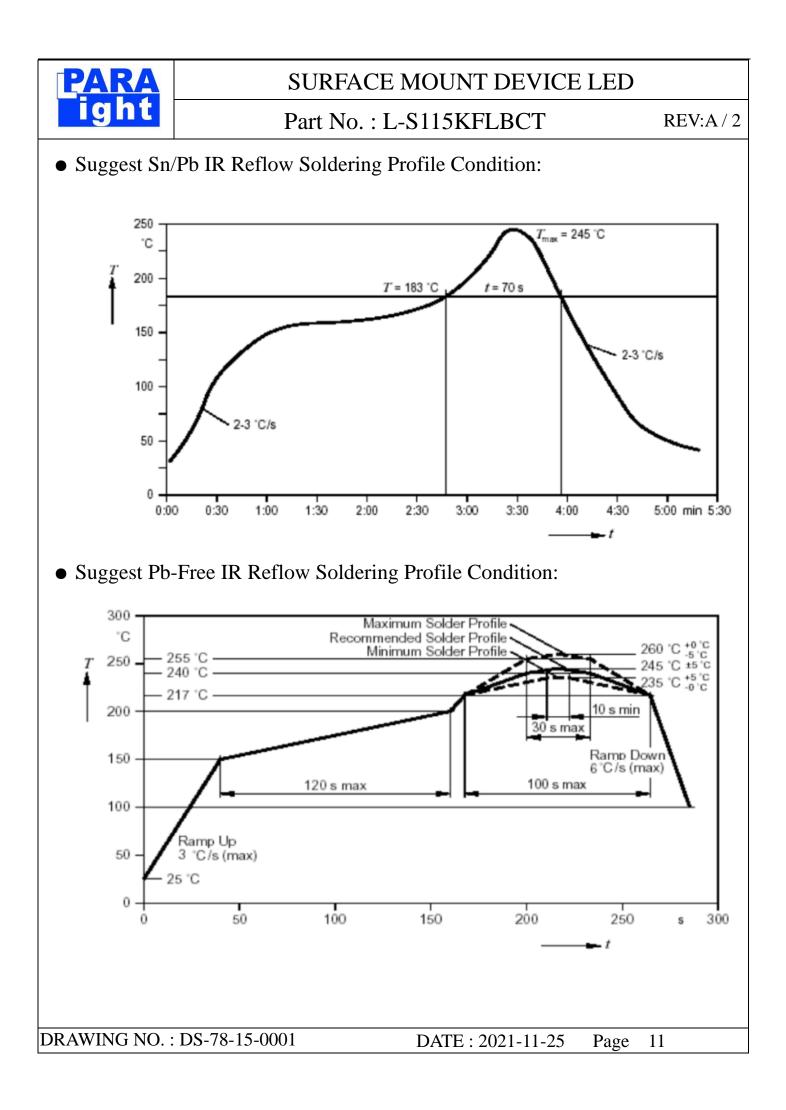
- \* If cleaning is required, use the following solutions for less than 1 minute and less than  $40^{\circ}$ C.
- \* Appropriate chemicals: Ethyl alcohol and isopropyl alcohol.
- \* Effect of ultrasonic cleaning on the LED resin body differs depending on such factors as the oscillator output, size of PCB and LED mounting method. The use of ultrasonic cleaning should be enforced at proper output after confirming there is no problem.

#### • Suggest Soldering Pad Dimensions



Direction of PWB camber and go to reflow furnace

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#### CAUTIONS

1. Application Limitation :

The LED's described here are intended to be used for ordinary electronic equipment (such as office equipment, communication equipment and household application).Consult PARA's sales in advance for information on application in which exceptional quality and reliability are required, particularly when the failure or malfunction of the LED's may directly jeopardize life or health (such as airplanes, automobiles, traffic control equipment, life support system and safety devices).

2.Storage :

Do not open moisture proof bag before the products are ready to use.

Before opening the package: The LEDs should be kept at  $30^{\circ}$ C or less and 90% RH or less. If the moisture absorbent material (silica gel) has faded away or the LEDs have exceeded the storage time, baking treatment should be performed using the following conditions. Baking treatment:  $60\pm5^{\circ}$ C for 24 hours.

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3.Soldering(Standard Process) :

Do not apply any stress to the lead frame during soldering while the LED is at high temperature. Recommended soldering condition.

Reflow Soldering :

Pre-heat 120~150 °C, 120sec. MAX., Peak temperature : 240 °C Max. Soldering time : 10 sec Max. Soldering Iron : (Not recommended)

Temperature 300 °C Max., Soldering time : 3 sec. Max.(one time only), power dissipation of iron : 20W Max. use SN60 solder of solder with silver content and don't to touch LED lens when soldering. Wave soldering :

Pre-heat 100  $^{\circ}$ C Max, Pre-heat time 60s Max, Solder wave 260  $^{\circ}$ C Max, Soldering time 5 sec. Max. preformed consecutively cooling process is required between 1st and 2nd soldering processes.

#### 4. Lead-Free Soldering

For Reflow Soldering :

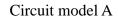
- 1、Pre-Heat Temp: 150-180°C,120sec.Max.
- 2. Soldering Temp : Temperature Of Soldering Pot Over 230°C,40sec.Max.
- 3 Peak Temperature :  $260^{\circ}$ C, 5sec.
- 4、Reflow Repetition: 2 Times Max.
- 5, Suggest Solder Paste Formula 93.3 Sn/3.1 Ag/3.1 Bi /0.5 Cu

For Soldering Iron (Not Recommended) :

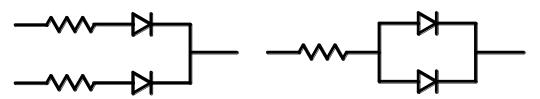
- 1. Iron Tip Temp :  $350^{\circ}$ C Max.
- 2、Soldering Iron: 30w Max.
- 3、Soldering Time : 3 Sec. Max. One Time.

For Dip Soldering :

- 1、Pre-Heat Temp:  $150^{\circ}$ C Max. 120 Sec. Max.
- 2、Bath Temp:  $265^{\circ}$ C Max.
- 3、 Dip Time : 5 Sec. Max.
- 5. Drive Method



Circuit model B



(A)Recommended circuit.

(B)The difference of brightness between LED's could be found due to the Vf-If characteristics of LED.

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